

SM5S10AHM3 thru SM5S43AHM3

Vishay General Semiconductor

Surface-Mount PAR[®] Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



DO-218 Compatible



LINKS TO ADDITIONAL RESOURCES



ges Marking

PRIMARY CHARACTERISTICS							
V _{WM}	10 V to 43 V						
V _{BR}	11.1 V to 52.8 V						
P _{PPM} (10 x 1000 μs)	3600 W						
P _{PPM} (10 x 10 000 μs)	2800 W						
PD	5 W						
I _{FSM}	500 A						
T _J max.	175 °C						
Polarity	Unidirectional						
Package	DO-218AC						

FEATURES

- Junction passivation optimized design passivated anisotropic rectifier technology
- T_J = 175 °C capability suitable for high reliability and automotive requirement
- Unidirectional
- Low leakage current
- Low forward voltage drop
- High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified available
 Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lightning, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AC

Molding compound meets UL 94 V-0 flammability rating Base P/NHM3 - RoHS-compliant, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 HM3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)									
PARAMETER		SYMBOL	VALUE	UNIT					
Peak pulse power dissipation	with 10/1000 µs waveform	D	3600	w					
	with 10/10 000 µs waveform	P _{PPM}	2800	vv					
Power dissipation on infinite heats	sink at T _A = 25 °C (fig. 1)	PD	5.0	W					
Peak pulse current with 10/1000	us waveform	I _{PPM} ⁽¹⁾	See next table	A					
Peak forward surge current 8.3 m	s single half sine-wave	I _{FSM}	500	A					
Operating junction and storage te	mperature range	T _J , T _{STG}	-55 to +175	°C					

Note

⁽¹⁾ Non-repetitive current pulse at $T_A = 25 \ ^{\circ}C$

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HALOGEN



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		EAKDO OLTAG V _{BR} (V)		TEST	STAND-OF F	MAXIMU M REVERSE	MAXIMUM REVERSE LEAKAGE	MAX. PEAK PULSE CURRENT	MAXIMU M CLAMPIN	$\begin{array}{c} \textbf{TYPICAL}\\ \textbf{TEMP.}\\ \textbf{COEFFICIE}\\ \textbf{NT OF V_{BR}}^{(1)}\\ \alpha \textbf{T}\\ (\%/^{\circ}\textbf{C}) \end{array}$
DEVICE TYPE	MIN.	NOM.	MAX.	I _T (mA)	VOLTAGE V _{WM} (V)	LEAKAGE AT V _{WM} Ι _D (μΑ)	AT V _{WM} T _J = 175 °C I _D (μΑ)	AT 10/1000 μs WAVEFORM (A)	G VOLTAGE AT I _{PPM} V _C (V)	
SM5S10AHM3	11.1	11.7	12.3	5.0	10.0	15	250	212	17.0	0.069
SM5S11AHM3	12.2	12.9	13.5	5.0	11.0	10	150	198	18.2	0.072
SM5S12AHM3	13.3	14.0	14.7	5.0	12.0	10	150	181	19.9	0.074
SM5S13AHM3	14.4	15.2	15.9	5.0	13.0	10	150	167	21.5	0.076
SM5S14AHM3	15.6	16.4	17.2	5.0	14.0	10	150	155	23.2	0.078
SM5S15AHM3	16.7	17.6	18.5	5.0	15.0	10	150	148	24.4	0.080
SM5S16AHM3	17.8	18.8	19.7	5.0	16.0	10	150	138	26.0	0.081
SM5S17AHM3	18.9	19.9	20.9	5.0	17.0	10	150	130	27.6	0.082
SM5S18AHM3	20.0	21.1	22.1	5.0	18.0	10	150	123	29.2	0.083
SM5S20AHM3	22.2	23.4	24.5	5.0	20.0	10	150	111	32.4	0.085
SM5S22AHM3	24.4	25.7	26.9	5.0	22.0	10	150	101	35.5	0.086
SM5S24AHM3	26.7	28.1	29.5	5.0	24.0	10	150	93	38.9	0.087
SM5S26AHM3	28.9	30.4	31.9	5.0	26.0	10	150	86	42.1	0.088
SM5S28AHM3	31.1	32.8	34.4	5.0	28.0	10	150	79	45.4	0.089
SM5S30AHM3	33.3	35.1	36.8	5.0	30.0	10	150	74	48.4	0.090
SM5S33AHM3	36.7	38.7	40.6	5.0	33.0	10	150	68	53.3	0.091
SM5S36AHM3	40.0	42.1	44.2	5.0	36.0	10	150	62	58.1	0.091
SM5S40AHM3	44.4	46.8	49.1	5.0	40.0	10	150	56	64.5	0.092
SM5S43AHM3	47.8	50.3	52.8	5.0	43.0	10	150	52	69.4	0.093

Notes

• For all types maximum V_F = 2.0 V at I_F = 100 A measured on 300 μ s square pulse width

⁽¹⁾ To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at T_J = V_{BR} at 25 °C x (1 + α T x (T_J - 25))

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	SYMBOL	VALUE	UNIT					
Typical thermal resistance	R _{0JA} ⁽¹⁾	55	°C/W					
rypicar merma resistance	R _{0JM} ⁽²⁾	0.45	°C/W					

Notes

⁽¹⁾ Thermal resistance junction-to-ambient to follow JEDEC[®]51-2A, device mounted on FR4 PCB, 2 oz. standard footprint

⁽²⁾ Thermal resistance junction-to-mount to follow JEDEC[®]51-14 using Transient Dual Interface Test Method (TDIM)



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ORDERING INFORMATION TABLE

www.vishay.com

Device code	SM	x	s	xx	Α	н	М3
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	1	2	3	4	5	6	7
	1	- Sur	face mo	unt			
	2	- Pov	ver dissi	pation F	P _D (5 = 5	5 W, 6 =	6 W, 8
	3	- Sta	ndard V	_F type			
	4	- Sta	nd-off v	oltage			
	5	- Bre	akdown	voltage	toleran	ce and p	olarity (
	6	- Qua	ality grad	de (H =	AEC-Q1	01 qual	ified, ot
	7		terial / E HS-com				

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
SM5S10AHM3/I ⁽¹⁾	2.505	Ι	750	13" diameter plastic tape and reel, anode towards the sprocket hole				

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

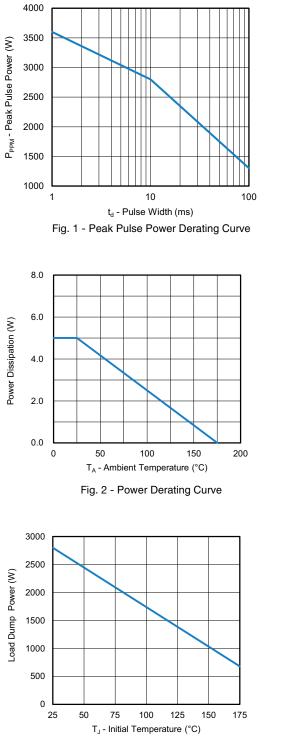


Fig. 3 - Load Dump Power Characteristics (10 ms Exponential Waveform)

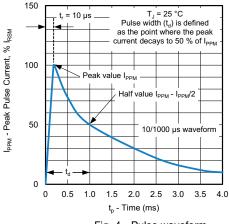
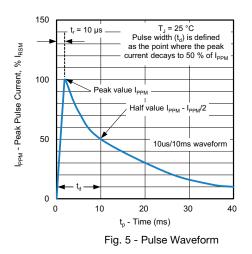


Fig. 4 - Pulse waveform



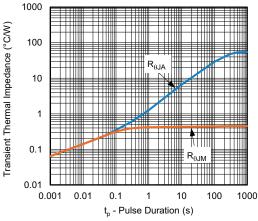


Fig. 6 - Typical Transient Thermal Impedance

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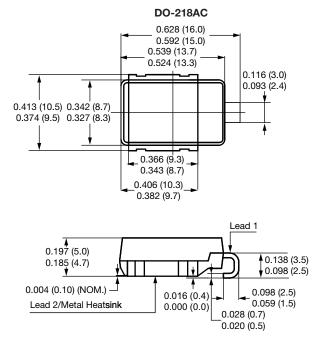
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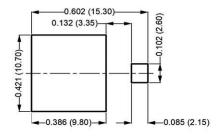
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout



Note

• Footprint in accordance with IPC 7351 standard



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